## Voltage Regulators, Peak Power Zener Surge Rated, 600 Watt

## BZG03C15 Series

The SMA series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable SURMETIC ${ }^{T M}$ package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications. This new line of 1.5 watt Zener diodes offers the following advantages:

## Specification Features

- Standard Zener Breakdown Voltage - 15 V to 150 V
- Peak Power 600 Watts @ $100 \mu \mathrm{~s}$
- ESD Rating of Class 3 (> 16 KV ) per Human Body Model
- Response Time is Typically < 1.0 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


## Mechanical Characteristics

CASE: Void-free, transfer-molded plastic
FINISH: All external surfaces are corrosion resistant and leads are readily solderable
MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:
$260^{\circ} \mathrm{C}$ for 10 Seconds
POLARITY: Cathode indicated by molded polarity notch or polarity band
MOUNTING POSITION: Any

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## PLASTIC SURFACE MOUNT <br> ZENER VOLTAGE REGULATORS 600 WATTS PEAK POWER



ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| BZG03C15G | SMA <br> (Pb-Free) | 5000/Tape \& Reel |
| BZG03C150G | SMA <br> (Pb-Free) | 5000/Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Peak Power Dissipation (Note 1) @ $\mathrm{T}_{\mathrm{L}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{P}}=100 \mu \mathrm{~s}$ | $\mathrm{P}_{\mathrm{ZSM}}$ | 600 | W |
| DC Power Dissipation @ $\mathrm{T}_{\mathrm{L}}=75^{\circ} \mathrm{C}$ | $\mathrm{P}_{\mathrm{D}}$ | 1.5 | W |
| Measured Zero Lead Length (Note 2) <br> Derate Above $75^{\circ} \mathrm{C}$ <br> Thermal Resistance, Junction-to-Lead | $\mathrm{R}_{\text {өJL }}$ | 20 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Forward Surge Current (Note 3) @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 50 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |
| Operating and Storage Temperature Range | $\mathrm{I}_{\mathrm{FSM}}$ | 40 | A |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. $100 \mu \mathrm{~s}$, non-repetitive square pulse
2. 1 in. square copper pad, FR-4 board
3. $1 / 2$ sine wave (or equivalent square wave), $\mathrm{PW}=8.3 \mathrm{~ms}$, duty cycle $=4$ pulses per minute maximum


SYMBOLS DEFINITIONS

| Symbol | Parameter |
| :---: | :--- |
| $\mathrm{I}_{\mathrm{PP}}$ | Maximum Reverse Peak Pulse Current |
| $\mathrm{V}_{\mathrm{C}}$ | Clamping Voltage @ $\mathrm{I}_{\mathrm{PP}}$ |
| $\mathrm{V}_{\mathrm{RWM}}$ | Working Peak Reverse Voltage |
| $\mathrm{I}_{\mathrm{R}}$ | Maximum Reverse Leakage Current @ $\mathrm{V}_{\mathrm{RWM}}$ |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown Voltage @ $\mathrm{I}_{\mathrm{T}}$ |
| $\mathrm{I}_{\mathrm{T}}$ | Test Current |
| $\mathrm{I}_{\mathrm{F}}$ | Forward Current |
| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage @ $\mathrm{I}_{\mathrm{F}}$ |

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted, $\mathrm{V}_{\mathrm{F}}=1.2 \mathrm{~V}$ Max. $@ \mathrm{I}_{\mathrm{F}}=0.5 \mathrm{~A}$ for all types $)$

| Device* | Device Marking | $\mathrm{V}_{\mathrm{RWM}}$ <br> (Note 4) <br> Volts | $\frac{\mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{RWM}}}{\mu \mathrm{~A}}$ | Breakdown Voltage |  |  |  | $\mathrm{Z}_{\text {zt }}$ @ IT |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\mathbf{V}_{\text {BR }}$ (V) (Note 5) |  |  | $\begin{gathered} @ \mathrm{I}_{\mathrm{T}} \\ \mathrm{~mA} \end{gathered}$ | $\begin{gathered} \text { Typ } \\ \hline \boldsymbol{\Omega} \end{gathered}$ | $\begin{gathered} \text { Max } \\ \hline \Omega \end{gathered}$ |
|  |  |  |  | Min | Nom | Max |  |  |  |
| BZG03C15, G | G15 | 11 | 1 | 13.8 | 15.0 | 15.6 | 50 | 5.0 | 10.0 |
| BZG03C150, G | G150 | 110 | 1 | 138 | 150 | 156 | 5 | 130 | 300 |

4. A transient suppressor is normally selected according to the working peak reverse voltage ( $\mathrm{V}_{\mathrm{RWM}}$ ), which should be equal to or greater than the DC or continuous peak operating voltage level
5. $\mathrm{V}_{\mathrm{BR}}$ measured at pulse test current $\mathrm{I}_{\mathrm{T}}$ at an ambient temperature of $25^{\circ} \mathrm{C}$
*The " G " suffix indicates Pb -Free package available.

## BZG03C15 Series

RATING AND TYPICAL CHARACTERISTIC CURVES


Figure 1. Pulse Rating Curve


Figure 2. Pulse Derating Curve


Figure 3. Typical Junction Capacitance


Figure 4. Steady State Power Derating


SCALE 1:1
SMA
CASE 403D
ISSUE J
DATE 22 OCT 2021

NOTES:

1. DIMENSIDNING AND TQLERANCING PER ANSI Y14.5M, 1982.
2. CDNTRDLLING DIMENSIDN: INCHES
3. DIMENSIDN b SHALL BE MEASURED WITHIN DIMENSIDN L.

| DIM | MILLIMETERS |  |  | INCHES |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
|  | MIN. | NDM. | MAX. | MIN. | NDM. | MAX. |
| A | 1.97 | 2.10 | 2.20 | 0.078 | 0.083 | 0.087 |
| A1 | 0.05 | 0.10 | 0.20 | 0.002 | 0.004 | 0.008 |
| b | 1.27 | 1.45 | 1.63 | 0.050 | 0.057 | 0.064 |
| C | 0.15 | 0.28 | 0.41 | 0.006 | 0.011 | 0.016 |
| D | 2.29 | 2.60 | 2.92 | 0.090 | 0.103 | 0.115 |
| E | 4.06 | 4.32 | 4.57 | 0.160 | 0.170 | 0.180 |
| HE $^{2}$ | 4.83 | 5.21 | 5.59 | 0.190 | 0.205 | 0.220 |
| L | 0.76 | 1.14 | 1.52 | 0.030 | 0.045 | 0.060 |



STYLE 1:
PIN 1. CATHODE (POLARITY BAND) 2. ANODE

STYLE 2:

| xxxx | $=$ Specific Device Code |
| :--- | :--- |
| A | $=$ Assembly Location |
| Y | $=$ Year |
| WW | $=$ Work Week |
| - | $=$ Pb-Free Package |

*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-F r e e$ indicator, " G " or microdot " F ", may or may not be present. Some products may not follow the Generic Marking.

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1N5369B 1 N747A 1N959B 1N964B 1N966B 1N972B NTE149A NTE5116A NTE5121A NTE5147A NTE5152A NTE5155A
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